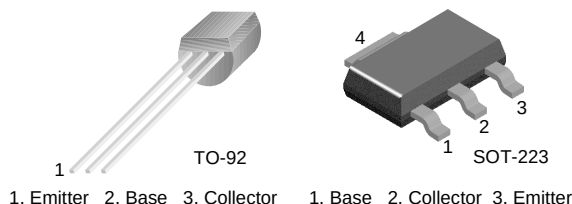


MPSA27/PZTA27

NPN General Purpose Amplifier

- This device is designed for applications requiring extremely high current gain at collector currents to 500mA.
- Sourced from process 03.
- See MPSA28 for characteristics.



Absolute Maximum Ratings* $T_A=25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CES}	Collector-Emitter Voltage	60	V
V_{CBO}	Collector-Base Voltage	60	V
V_{EBO}	Emitter-Base Voltage	10	V
I_C	Collector current - Continuous	800	mA
T_J, T_{stg}	Operating and Storage Junction Temperature	-55 ~ +150	$^{\circ}\text{C}$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- These ratings are based on maximum junction temperature of 150 degrees C.
- These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics $T_A=25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
Off Characteristics						
$V_{(BR)CES}$	Collector-Emitter Breakdown Voltage	$I_C = 100\mu\text{A}, V_{BE} = 0$	60			V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 10\mu\text{A}, I_C = 0$	60			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_C = 100\mu\text{A}, I_C = 0$	10			V
I_{CBO}	Collector Cutoff Current	$V_{CB} = 50\text{V}, I_E = 0$			100	nA
I_{CES}	Collector Cutoff Current	$V_{CE} = 50\text{V}, V_{BE} = 0$			500	nA
I_{EBO}	Emitter Cutoff Current	$V_{EB} = 10\text{V}, I_C = 0$			100	nA
On Characteristics						
h_{FE}	DC Current Gain	$I_C = 10\text{mA}, V_{CE} = 5.0\text{V}$ $I_C = 100\text{mA}, V_{CE} = 5.0\text{V}$	10000 10000			
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 100\text{mA}, I_B = 0.1\text{mA}$			1.5	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = 100\text{mA}, V_{CE} = 5.0\text{V}$			2.0	V
Small Signal Characteristics						
f_T	Current Gain Bandwidth Product	$I_C = 10\text{mA}, V_{CE} = 5.0\text{V},$ $f = 100\text{MHz}$	125			MHz

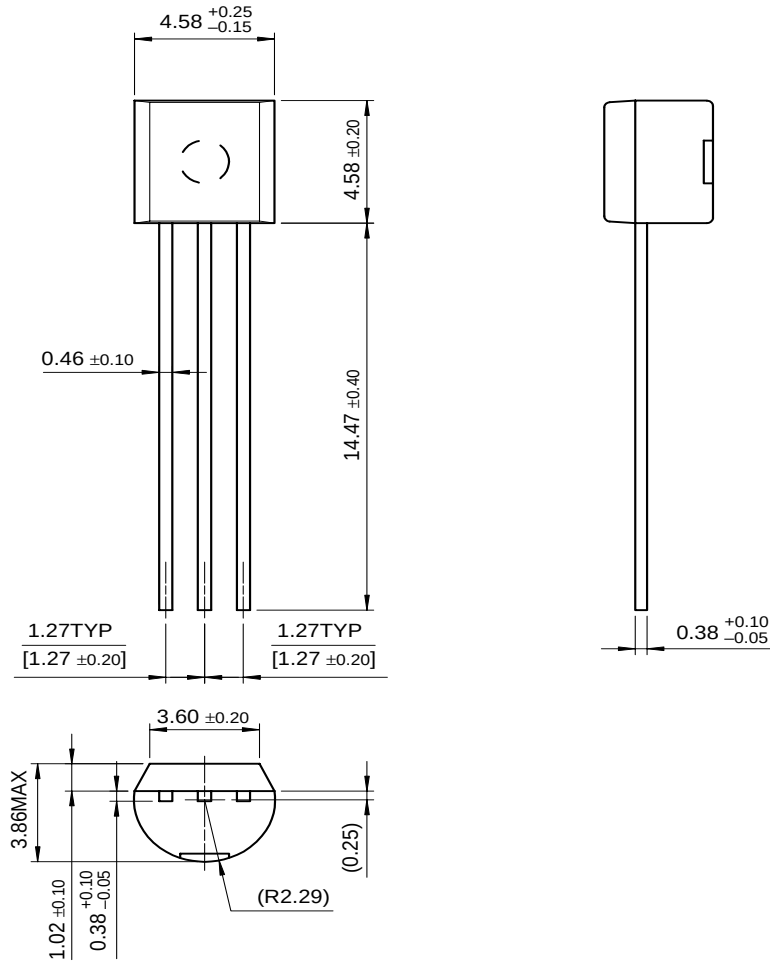
Thermal Characteristics $T_A=25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Max.		Units
		MPSA27	*PZTA27	
P_D	Total Device Dissipation Derate above 25°C	625 5.0	1000 8.0	mW mW/ $^{\circ}\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		$^{\circ}\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	125	$^{\circ}\text{C/W}$

* Device mounted on FR-4 PCB 36mm $\times$ 18mm $\times$ 1.5mm: mounting pad for the collector lead min. 6cm.

Package Dimensions

TO-92



Dimensions in Millimeters

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